

PNP BDT82 – BDT84 – BDT86 – BDT88

SILICON POWER TRANSISTORS

The BDT82 – BDT84 – BDT86 – BDT88 are epitaxial base transistors in a TO-220 plastic envelope.

They are intended for use in audio output stages and general amplifier and switching applications.

NPN complements are BDT81 – BDT83 – BDT85 – BDT87.

Compliance to RoHS.

ABSOLUTE MAXIMUM RATINGS

Symbol	Ratings			Value	Unit
			BDT82	-60	
V _{CEO}	Callactor Emitter Valtage	-IB = 0	BDT84	-80	V
	Collector-Emitter Voltage	-ID - U	BDT86	-100	V V
			BDT88	-120	
V _{CBO}			BDT82	-60	
	Collector Base Voltage	-IE = 0	BDT84	-80	
	Collector-Base Voltage	-IE - U	BDT86	-100	V
			BDT88	-120	
V _{EBO}	Emitter-Base Voltage -IC = 0			-7	V
Ic	Collector Current	-15	Α		
I _{CM}	Collector Peak Current			-20	Α
I _B	Base Current			-4	Α
Pt	Total Power Dissipation @ TC = 25°			125	W
$T_{\rm J}$	Junction Temperature			150	°C
T _{Stg}	Storage Temperature			-65 to +150	°C

THERMAL CHARACTERISTICS

Symbol	Ratings	Value	Unit
R_{thJa}	Thermal Resistance, Junction to Ambient	70	K/W
R_{thJmb}	Thermal Resistance, Junction to Mounting Base	1	K/W



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ELECTRICAL CHARACTERISTICS

TC=25°C unless otherwise noted

Symbol	Ratings	Test Condition(s)		Min	Тур	Max	Unit
		I _E =0A, V _{CB} = -60 V	BDT82				
	Collector Cutoff Current	I _E =0A, V _{CB} = -80 V	BDT84			-0.2	mA
I _{CB0}	Collector Cutoff Current	I _E =0A, V _{CB} = -100 V	BDT86	-	-	-0.2	IIIA
		I _E =0A, V _{CB} = -120 V	BDT88				
		V_{BE} =0, V_{CE} = -60V	BDT82				
	Collector Cutoff Current	V_{BE} =0, V_{CE} = -80V	BDT84			-1	m A
I _{CES}	Collector Cutoff Current	V_{BE} =0, V_{CE} = -100V	BDT86	-	-	-1	mA
		V_{BE} =0, V_{CE} = -120V	BDT88				
			BDT82				mA
	Emitter Cutoff Current	V _{EB} = -7 V	BDT84	<u> </u>	-	-0.1	
I _{EBO}	Emitter Cutoff Current	I _C =0	BDT86				
			BDT88				
			BDT82				
		I_C = -50mA	BDT84	40			
		V _{CE} = -10V	BDT86	40	_	_	
h	DC Current Gain (*)		BDT88				l _
h _{FE}	Do Current Gain ()		BDT82				_
		I _C = -5A V _{CE} = -4V	BDT84	40	-	-	
			BDT86				
			BDT88				
			BDT82				
V _{CE(SAT)}	Collector-Emitter Saturation Voltage (*)	I _C = -5A I _B = -0.5A	BDT84	_	-	-1	
V CE(SAI)			BDT86				
			BDT88				V
V _{BE(SAT)}			BDT82	- - -	-	-1.6	•
	Base-Emitter Saturation Voltage (*)	$I_C = -5A$ $I_B = -0.5A$	BDT84				
			BDT86				
			BDT88			1	
			BDT82	-	-	-1.5	V
V _{BE}	Base-Emitter Voltage (*)	I _C = -7A	BDT84	_			
		I _B = -0.7A	BDT86	1			
			BDT88				



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ELECTRICAL CHARACTERISTICS

TC=25°C unless otherwise noted

Symbol	Ratings	Test Condition(s)Sec	Min	Тур	Max	Unit
I _{S/B}	Second breakdown collector current	V_{CE} = -50 V, t_P = 100 ms	-2.5	-	-	Α
f _T	Transition frequency	V_{CE} = -10 V, I_{C} = -0.5 A, f=1 MHz	-	20	-	MHz
t _{on}	Turn-on time	I _C = -7 A	-	-	1	
T _{off}	Turn-off time	$I_{B1} = -I_{B2} = -0.7 \text{ A}$	-	_	2	μs

^(*) Pulse Duration = 300 μ s, $\delta \le 2\%$

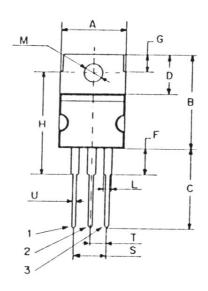


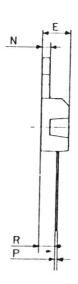
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MECHANICAL DATA CASE TO-220

DIMENSIONS (mm)				
	Min. Max.			
Α	9,90	10,30		
B C	15,65	15,90		
	13,20	13,40		
D	6,45	6,65		
F	4,30	4,50		
F	2,70	3,15		
G	2,60	3,00		
Н	15,75	17.15		
L M	1,15	1,40		
	3,50	3,70		
N	-	1,37		
Р	0,46	0,55		
R	2,50	2,70		
S	4,98	5,08		
S T U	2.49	2.54		
U	0,70	0,90		

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Pin 1 :	Base
Pin 2 :	Collector
Pin 3 :	Emitter
Package	Collector





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